

# **STF715 STN715**

## NPN MEDIUM POWER TRANSISTORS

Туре	Marking
STF715	715
STN715	N715

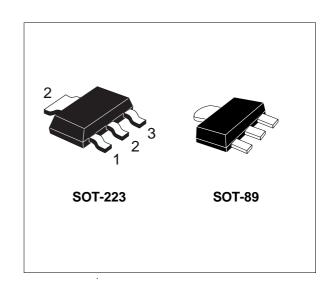
- SURFACE-MOUNTING DEVICES IN MEDIUM POWER SOT-223 AND SOT-89 PACKAGES
- AVAILABLE IN TAPE & REEL PACKING

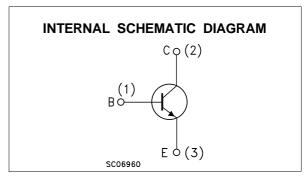
#### **APPLICATIONS**

- VOLTAGE REGULATION
- RELAY DRIVER
- GENERIC SWITCH

#### **DECRIPTION**

The STF715 and STN715 are NPN transistors manufactured using Planar Technology resulting in rugged high performance devices.





#### **ABSOLUTE MAXIMUM RATINGS**

Symbol	Parameter		Va	Value	
		Devices	STN715	STF715	
		Packages	SOT-223	SOT-89	
V <sub>CBO</sub>	Collector-Base Voltage (I <sub>E</sub> = 0)	Collector-Base Voltage (I <sub>E</sub> = 0)			
V <sub>CEO</sub>	Collector-Emitter Voltage (I <sub>B</sub> = 0)		8	V	
$V_{EBO}$	Emitter-Base Voltage (I <sub>C</sub> = 0)		5		V
Ic	Collector Current		1.5		Α
I <sub>CM</sub>	Collector Peak Current (t <sub>p</sub> < 5 ms)		2		Α
lΒ	Base Current		0.3		Α
$I_{BM}$	Base Peak Current (t <sub>p</sub> < 5 ms)		0.6		Α
P <sub>tot</sub>	Total Dissipation at T <sub>c</sub> = 25 °C		1.6	1.4	W
$T_{stg}$	Storage Temperature		-65 to	°C	
Tj	Max. Operating Junction Temperature		150		°C

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#### THERMAL DATA

			SOT-223	SOT-89	
R <sub>thj-amb</sub> •	Thermal Resistance Junction-ambient	Max	78	89	°C/W

<sup>•</sup> Device mounted on a PCB area of 1 cm<sup>2</sup>.

## **ELECTRICAL CHARACTERISTICS** ( $T_{case} = 25$ $^{\circ}C$ unless otherwise specified)

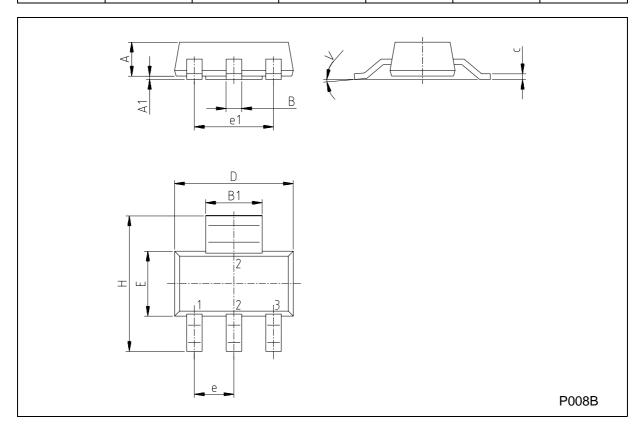
Symbol	Parameter	Test Conditions		Min.	Тур.	Max.	Unit
Ices	Collector Cut-off Current (V <sub>BE</sub> = 0)	V <sub>CE</sub> = 140 V				500	μΑ
ICEO	Collector Cut-off Current (I <sub>B</sub> = 0)	V <sub>CE</sub> = 80 V				1	mA
I <sub>EBO</sub>	Emitter Cut-off Current (I <sub>C</sub> = 0)	V <sub>EB</sub> = 5 V				100	μΑ
V <sub>CEO(sus)*</sub>	Collector-Emitter Sustaining Voltage (I <sub>B</sub> = 0)	I <sub>C</sub> = 10 mA		80			V
V <sub>CE(sat)*</sub>	Collector-Emitter Saturation Voltage	I <sub>C</sub> = 100 mA I <sub>C</sub> = 1 A	$I_B = 10 \text{ mA}$ $I_B = 100 \text{ mA}$			0.25 0.5	V V
V <sub>BE(sat)</sub> *	Base-Emitter Saturation Voltage	I <sub>C</sub> = 100 mA I <sub>C</sub> = 1 A	$I_B = 10 \text{ mA}$ $I_B = 100 \text{ mA}$			1 1.1	V V
h <sub>FE</sub> *	DC Current Gain	I <sub>C</sub> = 100 mA I <sub>C</sub> = 500 mA I <sub>C</sub> = 1 A	V <sub>CE</sub> = 2 V V <sub>CE</sub> = 2 V V <sub>CE</sub> = 2 V	140 80 40			
f⊤	Transition Frequency	I <sub>C</sub> = 0.1 A	V <sub>CE</sub> = 10 V		50		MHz

<sup>\*</sup> Pulsed: Pulse duration = 300 μs, duty cycle 1.5 %

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## **SOT-223 MECHANICAL DATA**

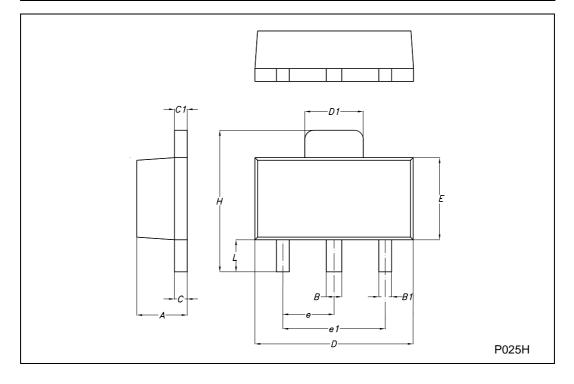
DIM.	mm			inch			
<b>2</b>	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.	
А			1.80			0.071	
В	0.60	0.70	0.80	0.024	0.027	0.031	
B1	2.90	3.00	3.10	0.114	0.118	0.122	
С	0.24	0.26	0.32	0.009	0.010	0.013	
D	6.30	6.50	6.70	0.248	0.256	0.264	
е		2.30			0.090		
e1		4.60			0.181		
E	3.30	3.50	3.70	0.130	0.138	0.146	
Н	6.70	7.00	7.30	0.264	0.276	0.287	
V			10°			10°	
A1		0.02					



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#### **SOT-89 MECHANICAL DATA**

DIM.	mm			mils		
Divi.	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
Α	1.4		1.6	55.1		63.0
В	0.44		0.56	17.3		22.0
B1	0.36		0.48	14.2		18.9
С	0.35		0.44	13.8		17.3
C1	0.35		0.44	13.8		17.3
D	4.4		4.6	173.2		181.1
D1	1.62		1.83	63.8		72.0
E	2.29		2.6	90.2		102.4
е	1.42		1.57	55.9		61.8
e1	2.92		3.07	115.0		120.9
Н	3.94		4.25	155.1		167.3
L	0.89		1.2	35.0		47.2



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